

FORM PTO-1449 (REV. 7-80)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO.  TI-33227.1		SERIAL NO.  TBD	
LIST OF DOCUMENTS CITED BY APPLICANT (Use several sheets if necessary)							
				APPLICANT: Xiaoju Wu			
				FILING DATE Herewith		GROUP TBD	
U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
RP		5,406,110	04/11/95	Kwon et al.	257	493	02/01/1994
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SU B CL AS S	TRANSLATION  YES      NO
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)							
RP		"Implementation of High Side High Voltage RESURF LDMOS in a Sub-half Micron Smart Power Technology", Zhu et al, Proceedings of 2001 International Symposium on Power Semiconductor Devices & ICs, June, 2001, pp 403-406					
RP		"16-60V Rated LDMOS Show Advanced Performance in an 0.72μ Evolution BiCMOS Power Technology", Tsai et al, IEEE, 1997, pp 367-370					
EXAMINER For Pompey				DATE CONSIDERED 3-2-05			
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							